

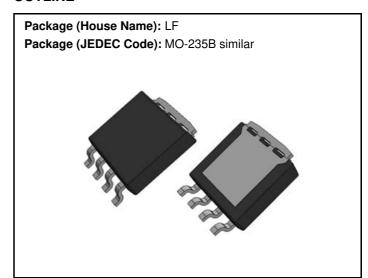
P46LF7R5SN

Power MOSFETs 75V, 46A, N-channel

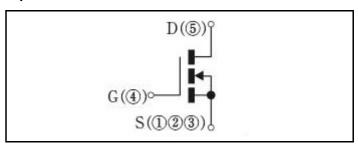
Feature

- N-channel
- Small SMD
- Large Current
- Low Ron
- 10V Gate Drive
- Low Capacitance
- · Halogen free
- · Pb free terminal
- RoHS:Yes

OUTLINE



Equivalent circuit



Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

| Item | Symbol | Conditions | Ratings | Unit |
|--------------------------------|-----------------|------------------------------|------------|------|
| Storage temperature | Tstg | | -55 to 175 | °C |
| Channel tempertature | Tch | | -55 to 175 | °C |
| Drain-source voltage | V_{DSS} | | 75 | V |
| Gate-source voltage | V_{GSS} | | ±20 | V |
| Continuous drain current(DC) | I _D | | 46 | Α |
| Continuous drain current(Peak) | I _{DP} | Pulse width 10μs, duty=1/100 | 138 | Α |
| Total power dissipation | P _T | | 168 | W |
| Single avalanche current | I _{AS} | Starting Tch=25°C Tch≦150°C | 28 | Α |
| Single avalanche energy | E _{AS} | Starting Tch=25°C Tch≦150°C | 88 | mJ |

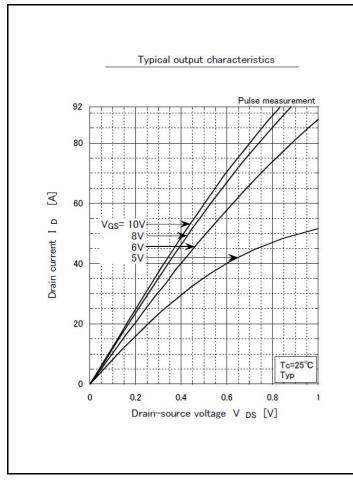
^{* :} See the original Specifications

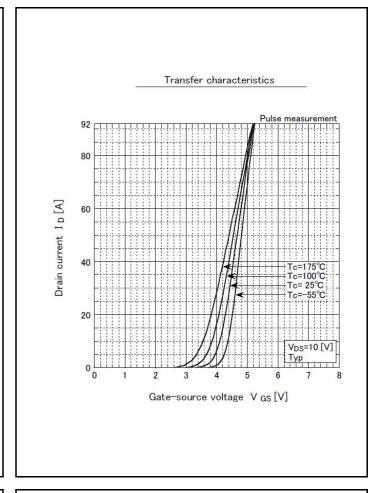
Electrical Characteristics (unless otherwise specified : Tc=25°C)

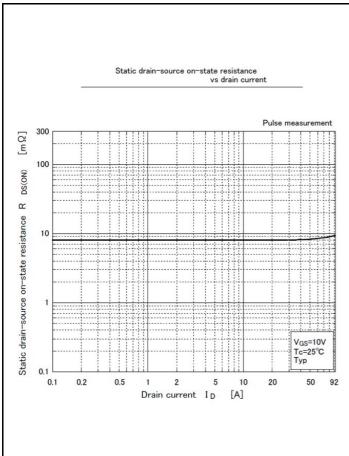
| Item | Symbol | Conditions | | Ratings | | |
|---|---------------------|---|-----|---------|------|------|
| | | | MIN | TYP | MAX | Unit |
| Drain-Source breakdown voltage | $V_{(BR)DSS}$ | ID=1mA, VGS=0V | 75 | | | ٧ |
| Zero gate voltage drain current | I _{DSS} | VDS=75V, VGS=0V | | | 1 | μA |
| Gate-source leakage current | I _{GSS} | VGS=±20V, VDS=0V | | | ±0.1 | μA |
| Forward transconductance | g _{fs} | ID=23A, VDS=10V | 10 | | | S |
| Static drain-source on-state resistance | R _{DS(ON)} | ID=23A, VGS=10V | | 0.008 | 0.01 | Ω |
| Gate threshold voltage | Vth | ID=1mA, VDS=10V | 2 | 3 | 4 | V |
| Source-drain diode forward voltage | V_{SD} | IS=46A, VGS=0V | | | 1.5 | ٧ |
| Thermal resistance | Rth(j-c) | Junction to case, with heatsink | | | 0.89 | °C/W |
| Total gate charge | Qg | VDD=60V, VGS=10V, ID=46A | | 48 | | nC |
| Gate to source charge | Qgs | VDD=60V, VGS=10V, ID=46A | | 13.5 | | nC |
| Gate to drain charge | Qgd | VDD=60V, VGS=10V, ID=46A | | 17 | | nC |
| Input capacitance | Ciss | VDS=25V, VGS=0V, f=1MHz | | 2380 | | pF |
| Reverce transfer capacitnce | Crss | VDS=25V, VGS=0V, f=1MHz | | 132 | | pF |
| Output capacitance | Coss | VDS=25V, VGS=0V, f=1MHz | | 272 | | pF |
| Turn-on delay time | td(on) | ID=23A, RL=1.63Ω, VDD=37.5V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V | | 5.7 | | ns |
| Rise time | tr | ID=23A, RL=1.63Ω, VDD=37.5V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V | | 10.5 | | ns |
| Turn-off delay time | td(off) | ID=23A, RL=1.63Ω, VDD=37.5V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V | | 29 | | ns |
| Fall time | tf | ID=23A, RL=1.63Ω, VDD=37.5V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V | | 10.5 | | ns |
| Diode reverse recovery time | trr | IF=46A, VGS=0V, di/dt=100A/μs | | 46 | | ns |
| Diode reverse recovery charge | Qrr | IF=46A, VGS=0V, di/dt=100A/μs | | 67 | | nC |

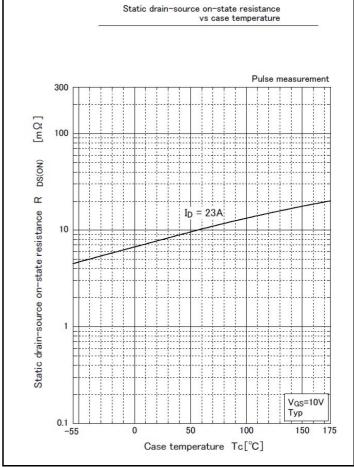
^{*} :See the original Specifications

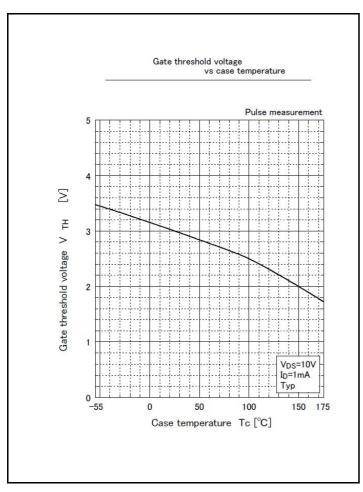
CHARACTERISTIC DIAGRAMS

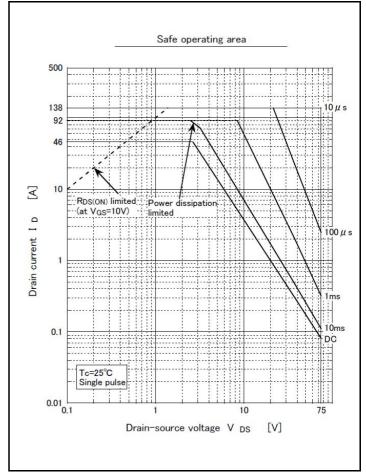


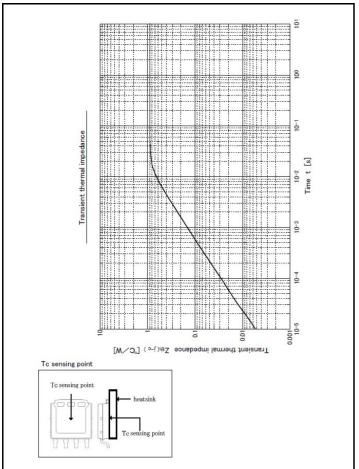


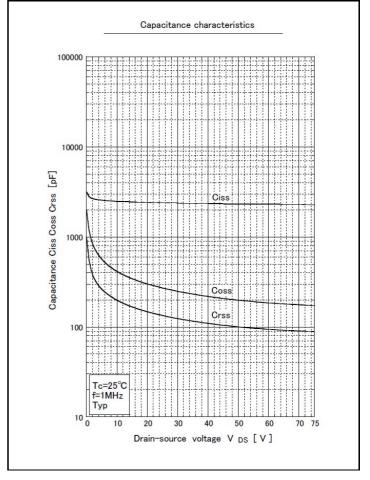


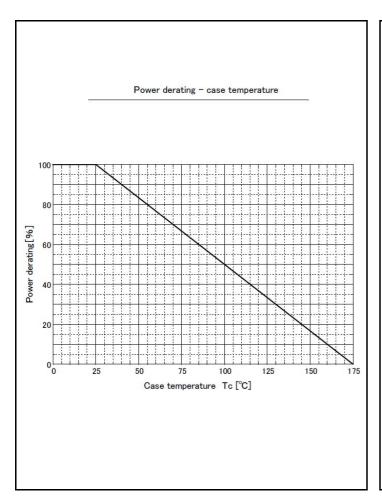


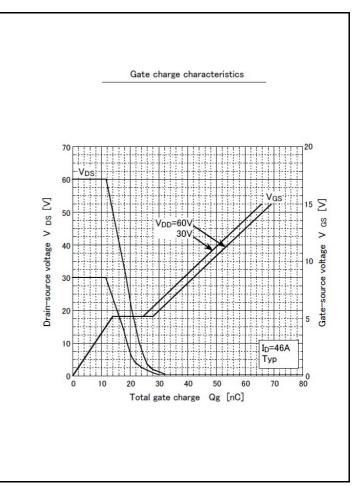


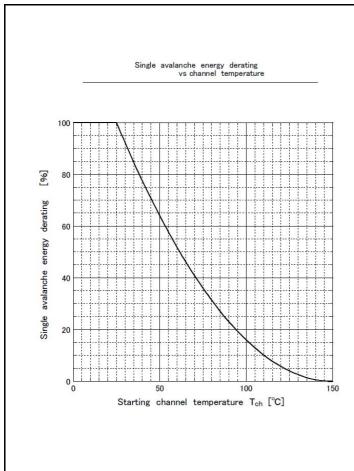




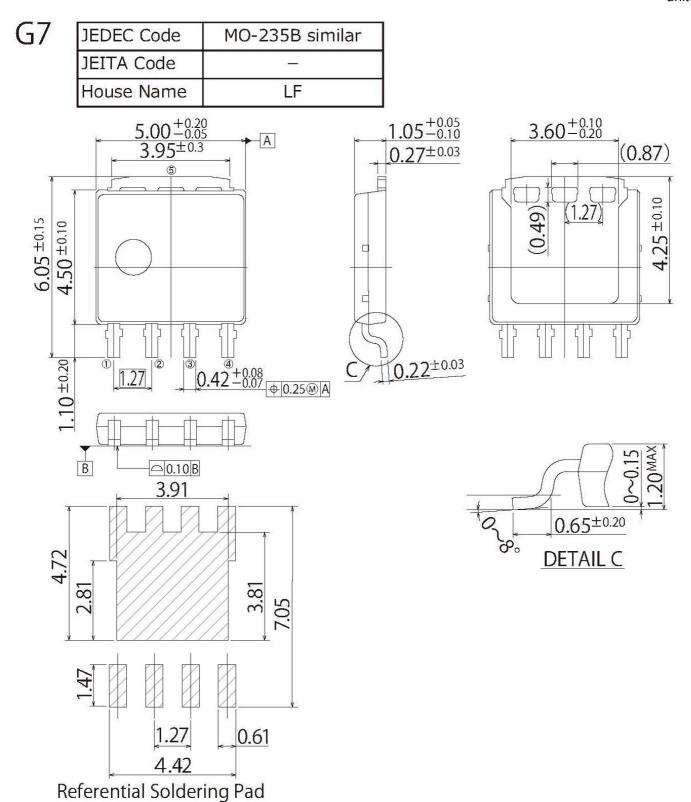








unit:mm



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